## NSN 5961-01-089-0781

Transistor - Page 1 of 1

A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-089-0781 **Inclosure Material:** Metal **Overall Length:** 24.90 millimeters **Overall Height:** 7.62 millimeters Overall Width: 19.33 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 breakdown voltage, collector-to-base, emitter open and 33.0 breakdown voltage, collector-to-emitter, base open and 65.0 collector to emitter reverse voltage, with base short-circuited to emitter and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 140.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: